

Fakultät für Ingenieurwesen Faculty of Engineering

COURSE DESCRIPTION – ACADEMIC YEAR 2023/2024

Course title	Dispositivi Elettronici
Course code	42409
Scientific sector	ING-INF/01
Degree	Bachelor in Electronics and Cyber-physical Systems (L-8)
Semester	1
Year	2
Credits	9
Modular	No

Total lecturing hours	54
Total tutorials and lab hours	36
Attendance	Preferrable. Non-attending students should contact the lecturer at the start of the course to agree on the modalities of the independent study
Prerequisites	Mathematical Analysis I, Mathematical Analysis II, Physics I, Physics II
Course page	Teams

Specific educational objectives	The objective of this course is an understanding of the physics and operation of semiconductor devices. Specifically, understanding of the formation and behavior of metal-semiconductor contacts, basic knowledge of nanotechnology and microfabrication, understanding of operation and design of MOSFETs, bipolar transistor and JFET, and understanding of the operation of memories, optical devices and sensors.

Lecturer	Prof. Paolo Lugli Dr. Martina Aurora Costa Angeli Dr. Soufiane Krik
Contact	<u>paolo.lugli@unibz.it</u> <u>martinaaurora.aostaangeli@unibz.it</u> <u>soufiane.krik@unibz.it</u>
Scientific sector of lecturer	ING/INF-01 – ELECTRONICS
Teaching language	Italian
Office hours	After consultation and agreement with lecturers
Lecturing assistant (if any)	Dr. Manuela Ciocca, Dr. Guglielmo Trentini
Contact LA	<u>manuela.ciocca@unibz.it</u> guglielmo.trentini@student.unibz.it
Office hours LA	After consultation and agreement with TAs

List of topics	 The topics covered include: physics of semiconductor materials (e.g., crystal structure, energy bands, density of states, dopants, equilibrium statistics, non-equilibrium behavior and electronic transport); nanotechnology; pn junctions and diodes; MOSFETs; JFETs; MESFETs bipolar junction transistors; optical devices; memories;
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	- sensors.
Teaching format	Frontal lectures, exercises, and laboratories.

Learning outcomes

Assessment	 The exam is composed of two parts: Written: students can take 2 midterm exams (if not passed, the students need to take the final written exam including all covered topics). Oral.
Assessment language	Italian
Evaluation criteria and criteria for awarding marks	 The assessment criteria will be: the accuracy of the answers given in the written examination, with particular attention to the resolution procedure adopted and the formal correctness of the same. the accuracy of the answers given in the oral examination, with particular attention to the terminology used.

Required readings	"Semiconductor Physics and Devices", Donald A. Neamen.
Supplementary readings	"Elettronica di Millman", Jacob Millman, Arvin Grabel, Pierangelo Terreni.

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